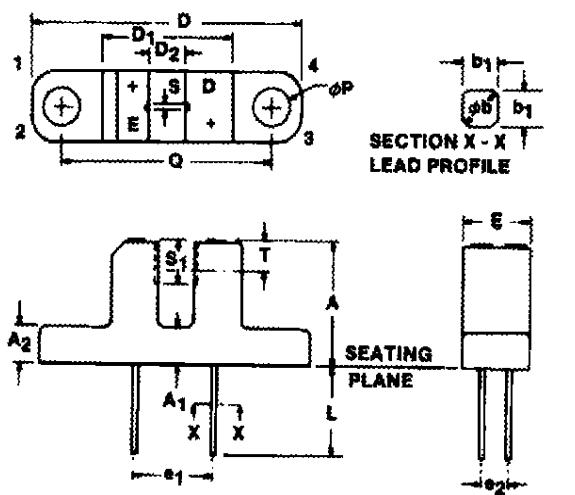




SLOTTED OPTICAL SWITCH

CNY29

PACKAGE DIMENSIONS



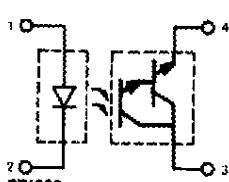
ST1339

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	19.7	21.9	.772	.833	
A ₁	3.0	3.2	.119	.126	
A ₂	3.0	3.2	.119	.126	
b ₂	.600	.750	.024	.030	2
b ₃	.50 NOM.		.020 NOM.		2
D	24.3	24.7	.957	.972	
D ₁	11.0	12.0	.437	.472	
D ₂	3.0	3.3	.119	.129	
e	6.9	7.5	.272	.295	
e ₁	2.3	2.8	.091	.110	
E	.615	.635	.243	.249	
L	6.00		.236		
b ₀	3.2	3.4	.126	.133	
Q	18.9	19.2	.745	.755	
S	.95	1.0	.034	.039	
S ₁	3.45	3.75	.136	.147	
T	2.6 NOM.		.103 NOM.		3

NOTES:

1. INCH DIMENSIONS ARE DERIVED FROM MILLIMETERS.
2. FOUR LEADS. LEAD CROSS SECTION IS CONTROLLED BETWEEN 1.27mm (.050") FROM SEATING PLANE AND THE END OF THE LEADS.
3. THE SENSING AREA IS DEFINED BY THE "S" DIMENSION AND BY DIMENSION "T" $\pm 0.75\text{mm}$ ($\pm .030$ INCH).

PACKAGE OUTLINE



ST1609

DESCRIPTION

The CNY29 is a gallium arsenide infrared emitting diode coupled with a silicon photodarlington in a plastic housing. The gap in the housing provides a means of interrupting the signal with tape, cards, shaft encoders, or other opaque material, switching the output from an "ON" to an "OFF" state.

FEATURES

- Opaque housing
- Low cost
- .035" apertures
- European "Pro Electron" registered



SLOTTED OPTICAL SWITCH

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ Unless Otherwise Specified)

Storage Temperature	-55°C to +85°C
Operating Temperature	-55°C to +85°C
Soldering:		
Lead Temperature (Iron)	240°C for 5 sec. ^(A)
Lead Temperature (Flow)	260°C for 10 sec. ^(B)
INPUT DIODE		
Continuous Forward Current	60 mA
Reverse Voltage	3.0 Volts
Power Dissipation	100 mW ^(D)
OUTPUT DARLINGTON		
Collector-Emitter Voltage	25 Volts
Emitter-Collector Voltage	7 Volts
Power Dissipation	150 mW ^(E)

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless Otherwise Specified)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
INPUT DIODE						
Forward Voltage	V_F	—	—	1.7	V	$I_F = 10 \text{ mA}$
Reverse Leakage Current	I_R	—	—	10	μA	$V_R = 2 \text{ V}$
OUTPUT DARLINGTON						
Emitter-Collector Breakdown	BV_{CEO}	7.0	—	—	V	$I_C = 100 \mu\text{A}, Ee=0$
Collector-Emitter Breakdown	BV_{CEO}	25	—	—	V	$I_C = 10 \text{ mA}, Ee=0$
Collector-Emitter Leakage	I_{CEO}	—	—	100	nA	$V_{CE} = 10 \text{ V}, Ee=0$
COUPLED						
On-State Collector Current	$I_{C(ON)}$	2.5	—	—	mA	$I_C = 20 \text{ mA}, V_{CE} = 10 \text{ V}$
Saturation Voltage	$V_{CE(SAT)}$	—	—	1.2	V	$I_C = 20 \text{ mA}, I_C = 0.5 \text{ mA}$
Turn-On Time	t_{on}	—	150	—	μs	$I_C = 2.0 \text{ mA}, V_{CE} = 10 \text{ V}, R_L = 750\Omega$
Turn-Off Time	t_{off}	—	150	—	μs	$I_C = 2.0 \text{ mA}, V_{CE} = 10 \text{ V}, R_L = 750\Omega$

NOTES

- Derate power dissipation linearly 1.67 mW/ $^\circ\text{C}$ above 25°C.
- Derate power dissipation linearly 2.50 mW/ $^\circ\text{C}$ above 25°C.
- RMA flux is recommended.
- Methanol or Isopropyl alcohols are recommended as cleaning agents.
- Soldering iron tip $1\frac{1}{8}$ " (1.6 mm) from housing.



SLOTTED OPTICAL SWITCH

TYPICAL CHARACTERISTICS

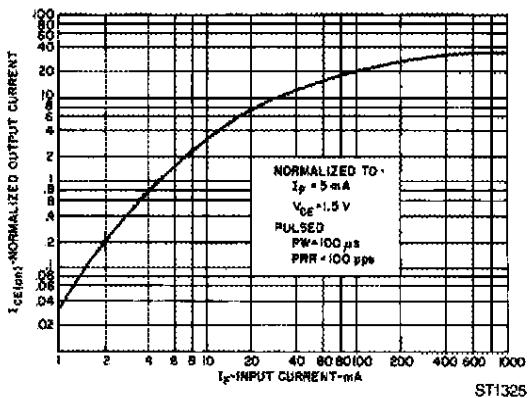


Fig. 1. Output Current vs. Input Current

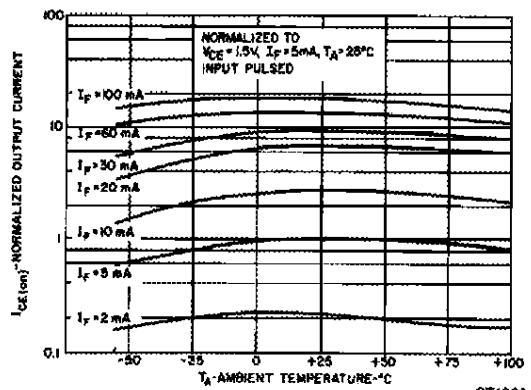


Fig. 2. Output Current vs. Temperature

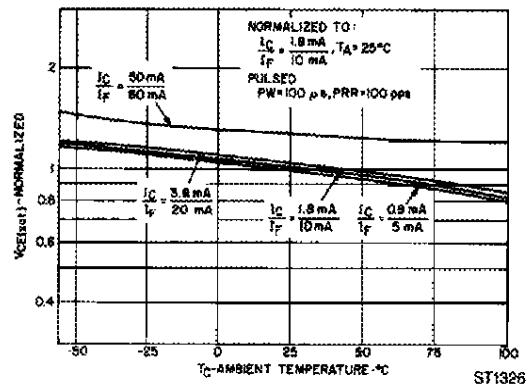


Fig. 3. V_{CESAT} vs. Temperature

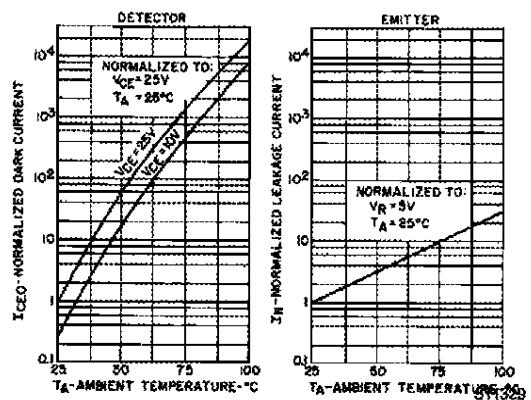


Fig. 4. Leakage Current vs. Temperature

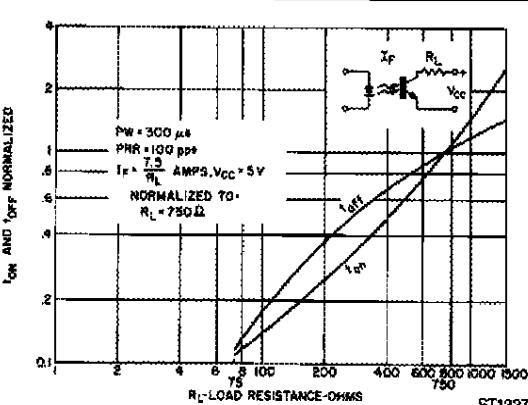


Fig. 5. Switching Speed vs. R_L

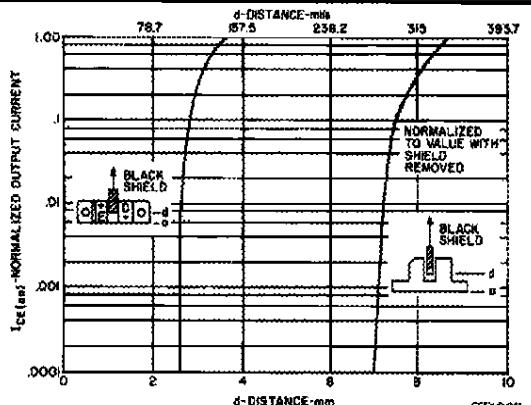


Fig. 6. Output Current vs. Distance